Features

High Performance Programmable Logic Device

7.5 ns Max Propagation Delay Up to 166 MHz Operation

5 V ± 10% Operation

 Fully Compatible with Standard 22V10 Identical Functionality/Fuse-Map

TTL Compatible Inputs and Outputs

10 μA Leakage Maximum

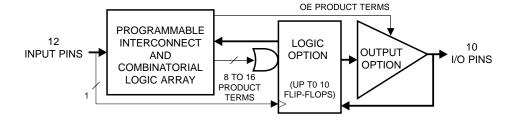
- Reprogrammable Tested 100% for Programmability
- High Reliability

Proven UV Erasable CMOS Technology 2000 V ESD Protection

200 mA Latch-Up Protection

- Full Military, Commercial and Industrial Temperature Ranges
- Dual-In-Line and Surface Mount Packages with Standard Pinouts

Logic Diagram



Description

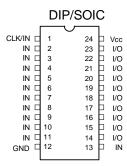
The AT22V10B is an ultra-high performance CMOS Programmable Logic Device (PLD). Speeds down to 7.5 ns and operation up to 166 MHz are offered. All pins offer a low \pm 10 μA leakage.

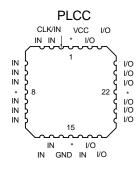
The AT22V10B logic functionality is fully compatible with the standard 22V10. The 12 dedicated inputs and ten configurable I/O pins allow implementation of logic requiring up to 22 input signals. The AT22V10B also provides individual output enable product terms for each of the ten I/Os.

(continued)

Pin Configurations

Pin Name	Function
CLK/IN	Clock and Logic Input
IN	Logic Inputs
I/O	Bidirectional Buffers
*	No Internal Connection
VCC	+5 V Supply





High Speed
UV Erasable
Programmable
Logic Device

0226B





Description (Continued)

The AT22V10B incorporates a variable product term architecture. Each output is allocated from eight to 16 product terms, which allows highly complex logic functions to be realized.

The AT22V10B includes two additional product terms to provide synchronous preset and asynchronous reset. These terms

are common to all ten registers. All registers are automatically cleared upon power up.

Register preload simplifies testing. A security fuse prevents unauthorized copying of programmed fuse patterns.

Absolute Maximum Ratings*

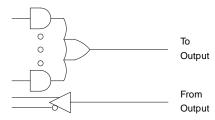
Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on Any Pin with Respect to Ground2.0 V to +7.0 $V^{(1)}$
Voltage on Input Pins with Respect to Ground During Programming2.0 V to +14.0 V ⁽¹⁾
Programming Voltage with Respect to Ground2.0 V to +14.0 $V^{(1)}$
Integrated UV Erase Dose7258 W-sec/cm ²

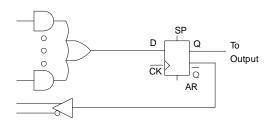
*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note:

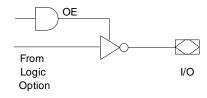
1. Minimum voltage is -0.6 V dc which may undershoot to -2.0 V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC}+0.75 V dc which may overshoot to +7.0 V for pulses of less than 20 ns.

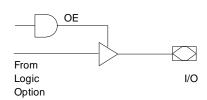
Logic Options





Output Options





D.C. and A.C. Operating Conditions

	Commercial AT22V10B -7	Commercial AT22V10B -10	Industrial AT22V10B -10	Military AT22V10B -10
Operating Temperature (Case)	0°C - 70°C	0°C - 70°C	-40°C - 85°C	-55°C - 125°C
Vcc Power Supply	5 V ± 5%	5 V \pm 10%	$5~V\pm10\%$	5 V ± 10%

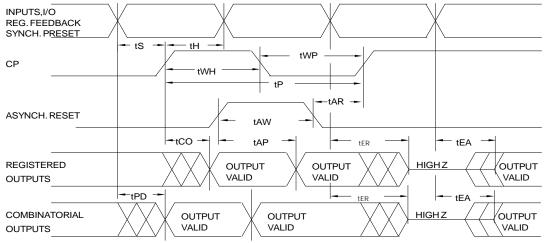
D.C. Characteristics

Symbol	Parameter	Condition				Max	Units
ILI	Input Load Current	$V_{IN} = -0.1 \text{ V to V}_{CC}$	$V_{IN} = -0.1 \text{ V to V}_{CC}+1 \text{ V}$			10	μΑ
ILO	Output Leakage Current	$V_{OUT} = -0.1 \text{ V to } V_{OUT}$	cc+0.1 V			10	μΑ
loo	Dowar Supply Current	$f = 0 MHz to F_{MAX}$	= 0 MHz to F _{MAX} , V _{CC} = MAX, Com.			140	mA
Icc	Power Supply Current	$V_{IN} = GND$, Output	s Open	Ind., Mil.		160	mA
los (1)	Output Short Circuit Current	V _{OUT} = 0.5 V	V _{OUT} = 0.5 V			-120	mA
VIL	Input Low Voltage						V
VIH	Input High Voltage						V
	Output Low Voltage	V _{IN} = V _{IH} or V _{IL} , V _{CC} = MIN	IoL = 16 mA	Com.,Ind.		0.5	V
VoL			I _{OL} = 12 mA	Mil.		0.5	V
			I _{OL} = 24 mA	Com.		0.8	V
Voн	Output High Voltage	V _{IN} = V _{IH} or V _{IL} , V _{CC} = MIN	I _{OH} = -4.0 mA		2.4		V

Notes: 1. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec.



A.C. Waveforms (1)



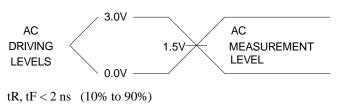
Note: 1. Timing measurement reference is 1.5 V. Input AC driving levels are 0.0 V and 3.0 V, unless otherwise specified.

A.C. Characteristics

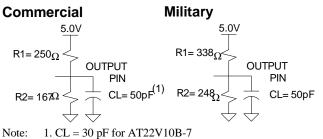
		AT22V10B-7		AT22V10B-10				
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Units
t _{PD}	Input or Feedback to Non-Registered Output		5	7.5		6	10	ns
t _{EA}	Input to Output Enable		5	7.5		6	10	ns
tER	Input to Output Disable		5	7.5		6	10	ns
tcF (1)	Clock to Feedback	0	1	2	0	1	2	ns
tco	Clock to Output	0	3.5	5.5	0	4	7	ns
ts	Input or Feedback Setup Time	3.5	2		5	3		ns
tH	Hold Time	0			0			ns
t₽	Clock Period	6			7			ns
twL (1)	Clock Width Low	3			3.5			ns
twH	Clock Width High	3			3.5			ns
	External Feedback 1/(ts+tco)			111			83	MHz
FMAX	Internal Feedback 1/(t _S + t _{CF})			166			142	MHz
	No Feedback 1/(tp)			166			142	MHz
t _{AW}	Asynchronous Reset Width	6	3		7	4		ns
tar	Asynchronous Reset, Synchronous Preset, Recovery Time	7	4		8	5		ns
t _{AP}	Asynchronous Reset to Registered Output Reset		6	10		8	14	ns

Note: 1. This parameter is only sampled and is not 100% tested.

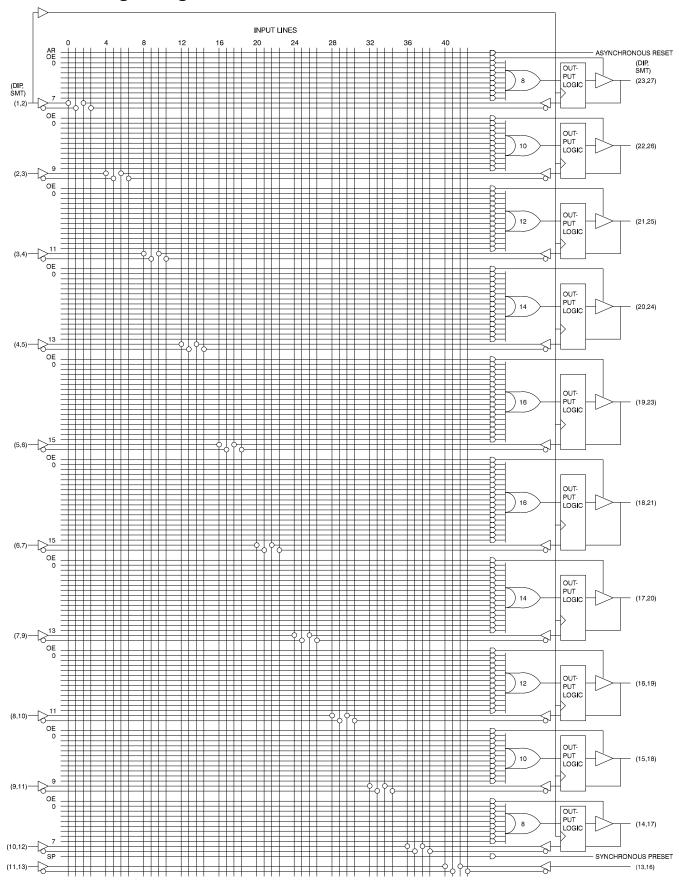
Input Test Waveforms and Measurement Levels



Output Test Loads:



Functional Logic Diagram AT22V10B

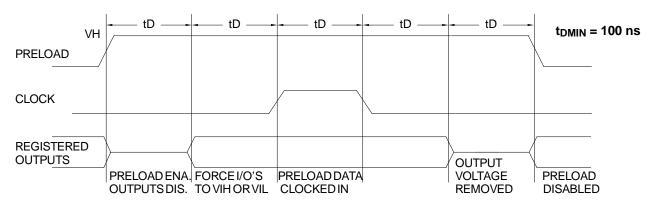




Preload of Registered Outputs

The registers in the AT22V10B are provided with circuitry to allow loading of each register asynchronously with either a high or a low. This feature will simplify testing since any state can be forced into the registers to control test sequencing. A V_{IH} level on the I/O pin will force the register high; a V_{IL} will force it low, independent of the polarity bit (CO) setting. The preload state is entered by placing an 10.5-V to 12-V signal on pin 8 on DIPs, and pin 10 on SMPs. When the clock pin is pulsed high, the data on the I/O pins is placed into the ten registers.

Level forced on registered output pin during preload cycle	Register state after cycle
V _{IH}	High
VIL	Low

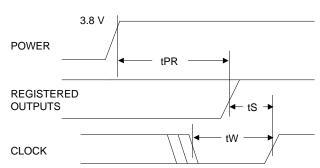


Power Up Reset

The registers in the AT22V10B are designed to reset during power up. At a point delayed slightly from V_{CC} crossing 3.8 V, all registers will be reset to the low state. The output state will depend on the polarity of the output buffer.

This feature is critical for state machine initialization. However, due to the asynchronous nature of reset and the uncertainty of how V_{CC} actually rises in the system, the following conditions are required:

- 1) The V_{CC} rise must be monotonic,
- 2) After reset occurs, all input and feedback setup times must be met before driving the clock pin high, and
- 3) The clock must remain stable during tpR.



Parameter	Description	Min	Тур	Max	Units
t _{PR}	Power-Up Reset Time		600	1000	ns

Pin Capacitance $(f = 1 \text{ MHz}, T = 25^{\circ}\text{C})^{(1)}$

	Тур	Max	Units	Conditions
C _{IN}	5	8	pF	$V_{IN} = 0 V$
Cout	6	8	pF	V _{OUT} = 0 V

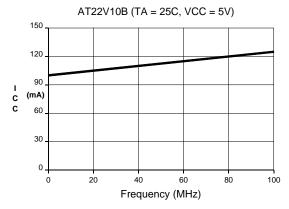
Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

Erasure Characteristics

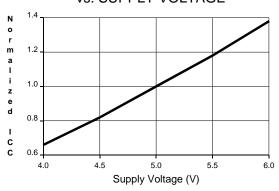
The entire fuse array of an AT22V10B is erased after exposure to ultraviolet light at a wavelength of 2537 Å. Complete erasure is assured after a minimum of 20 minutes exposure using 12,000 $\mu\text{W/cm}^2$ intensity lamps spaced one inch away from the chip. Minimum erase time for lamps at other intensity ratings can be

calculated from the minimum integrated erasure dose of 15 W•sec/cm². To prevent unintentional erasure, an opaque label is recommended to cover the clear window on any UV erasable PLD which will be subjected to continuous fluorescent indoor lighting or sunlight.

SUPPLY CURRENT vs. INPUT FREQUENCY

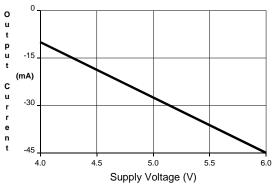


NORMALIZED SUPPLY CURRENT vs. SUPPLY VOLTAGE



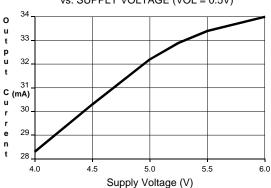
OUTPUT SOURCE CURRENT

vs. SUPPLY VOLTAGE (VOH = 2.4V)

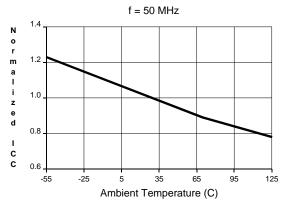


OUTPUT SINK CURRENT

vs. SUPPLY VOLTAGE (VOL = 0.5V)

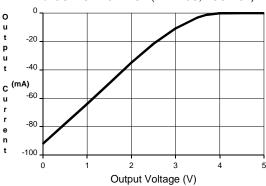


NORMALIZED ICC vs. AMBIENT TEMP.



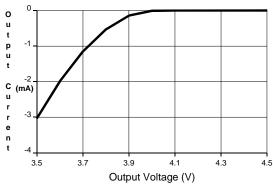
OUTPUT SOURCE CURRENT

vs. OUTPUT VOLTAGE (TA = 25C, VCC = 5V)



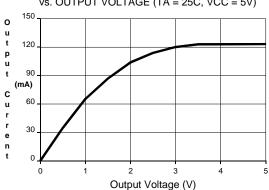
OUTPUT SOURCE CURRENT

vs. OUTPUT VOLTAGE (TA = 25C, VCC = 5V)



OUTPUT SINK CURRENT

vs. OUTPUT VOLTAGE (TA = 25C, VCC = 5V)

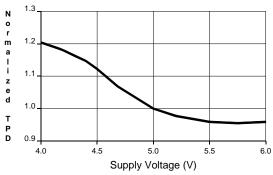






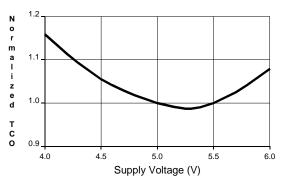
NORMALIZED TPD

vs. SUPPLY VOLTAGE



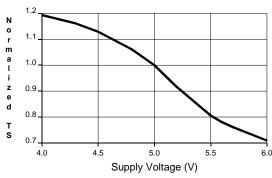
NORMALIZED TCO

vs. SUPPLY VOLTAGE



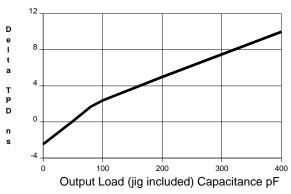
NORMALIZED TS

vs. SUPPLY VOLTAGE



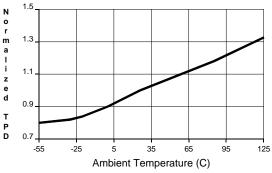
DELTA TPD vs. OUTPUT LOADING

(VCC = 4.5V, OUTPUT LOAD = COMMERCIAL)



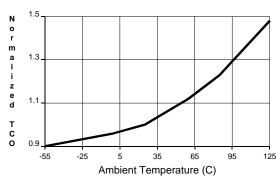
NORMALIZED TPD

vs. TEMPERATURE



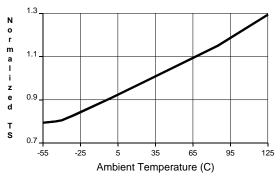
NORMALIZED TCO

vs. TEMPERATURE



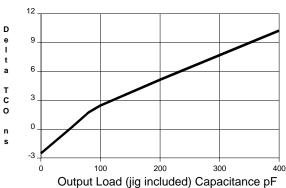
NORMALIZED TS

vs. TEMPERATURE



DELTA TCO vs. OUTPUT LOADING

(VCC = 4.5V, OUTPUT LOAD = COMMERCIAL)



Ordering Information

t _{PD} (ns)	ts (ns)	tco (ns)	Ordering Code	Package	Operation Range
7.5	3.5	5.5	AT22V10B-7DC AT22V10B-7JC AT22V10B-7PC	24DW3 28J 24P3	Commercial (0°C to 70°C)
10	5	7	AT22V10B-10DC AT22V10B-10GC AT22V10B-10JC AT22V10B-10PC AT22V10B-10SC	24DW3 24D3 28J 24P3 24S	Commercial (0°C to 70°C)
			AT22V10B-10DI AT22V10B-10GI AT22V10B-10JI AT22V10B-10PI AT22V10B-10SI	24DW3 24D3 28J 24P3 24S	Industrial (-40°C to 85°C)
			AT22V10B-10DM AT22V10B-10GM AT22V10B-10LM AT22V10B-10NM	24DW3 24D3 28LW 28L	Military (-55°C to 125°C)
			AT22V10B-10DM/883 AT22V10B-10GM/883 AT22V10B-10LM/883 AT22V10B-10NM/883 AT22V10B-12LM/883 AT22V10B-12NM/883	24DW3 24D3 28LW 28L 28LW 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant
10	5	7	5962-87539 06 LA 5962-87539 06 3X	24DW3 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant

	Package Type				
24DW3	24 Lead, 0.300" Wide, Windowed, Ceramic Dual Inline Package (Cerdip)				
24D3	24 Lead, 0.300" Wide, Non-Windowed (OTP), Ceramic Dual Inline Package (Cerdip)				
28J	28 Lead, Plastic J-Leaded Chip Carrier OTP (PLCC)				
28LW	28LW 28 Pad, Windowed, Ceramic Leadless Chip Carrier (LCC)				
28L	28L 28 Pad, Non-Windowed, Ceramic Leadless Chip Carrier OTP (LCC)				
24P3	24 Lead, 0.300" Wide, Plastic Dual Inline Package OTP (PDIP)				
24S	24 Lead, 0.300" Wide, Plastic Gull Wing Small Outline OTP (SOIC)				

